# **Power MOSFET** 200 mA, 50 V

# N-Channel SOT-23

Typical applications are DC-DC converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

#### Features

- Low Threshold Voltage (V<sub>GS(th)</sub>: 0.5 V-1.5 V) Makes it Ideal for Low Voltage Applications
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Pb–Free Packages are Available

<b>WAANNOW HATINGS</b> ( $T_A = 25$ C unless otherwise holed)					
Rating	Symbol	Value	Unit		
Drain-to-Source Voltage	V <sub>DSS</sub>	50	Vdc		
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	± 20	Vdc		
Drain Current – Continuous @ T <sub>A</sub> = 25°C – Pulsed Drain Current (t <sub>p</sub> ≤ 10 μs)	I <sub>D</sub> I <sub>DM</sub>	200 800	mA		
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	225	mW		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C		
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	556	°C/W		
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	TL	260	°C		

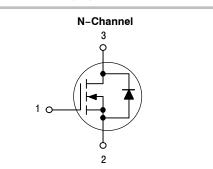
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

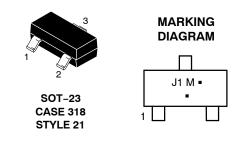


# **ON Semiconductor®**

http://onsemi.com

200 mA, 50 V  $R_{DS(on)} = 3.5 \Omega$ 





= Device Code J1

М = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may

vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BSS138LT1	SOT-23	3000 Tape & Reel
BSS138LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
BSS138LT3	SOT-23	10,000 Tape & Reel
BSS138LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BSS138LT1/D



# MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

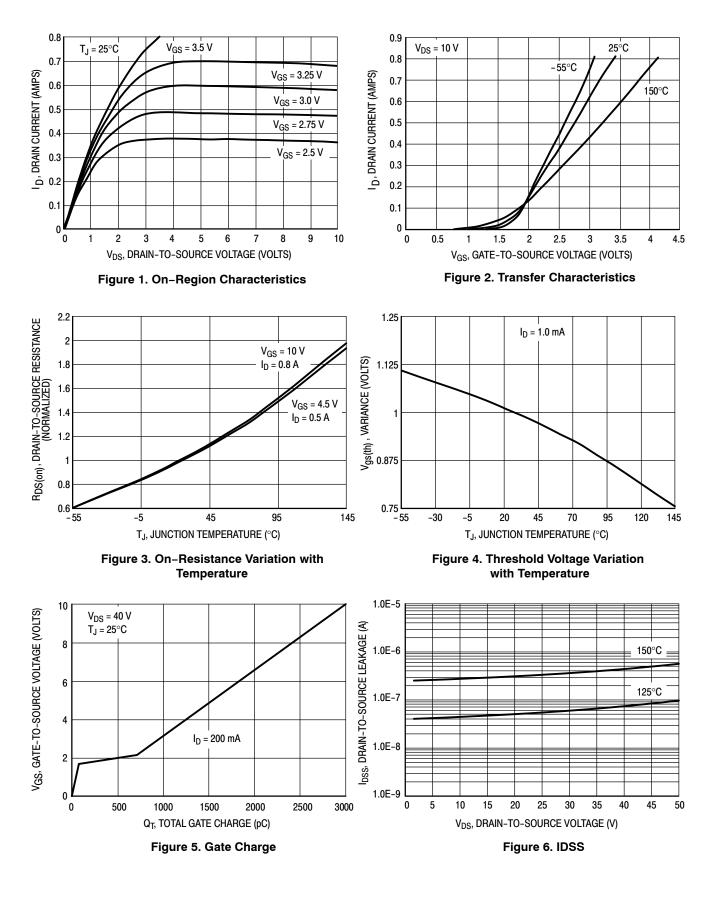
# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage ( $V_{GS}$ = 0 Vdc, I <sub>D</sub> = 250 $\mu$ Adc)			50	-	-	Vdc
Zero Gate Voltage Drain Current $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, 25^{\circ}\text{C})$ $(V_{DS} = 50 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, 25^{\circ}\text{C})$ $(V_{DS} = 50 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, 150^{\circ}\text{C})$					0.1 0.5 5.0	μAdc
Gate-Source Leakage Current	I <sub>GSS</sub>	-	-	±0.1	μAdc	
ON CHARACTERISTICS (Note 1	)					
$\label{eq:Gate-Source Threshold Voltage} \begin{aligned} & \text{Gate-Source Threshold Voltage} \\ & (\text{V}_{DS} = \text{V}_{GS}, \ \text{I}_{D} = 1.0 \ \text{mAdc}) \end{aligned}$	V <sub>GS(th)</sub>	0.5	-	1.5	Vdc	
Static Drain-to-Source On-Resistance ( $V_{GS}$ = 2.75 Vdc, $I_D$ < 200 mAdc, $T_A$ = -40°C to +85°C) ( $V_{GS}$ = 5.0 Vdc, $I_D$ = 200 mAdc)		r <sub>DS(on)</sub>		5.6 -	10 3.5	Ω
Forward Transconductance $(V_{DS} = 25 \text{ Vdc}, I_D = 200 \text{ mAd})$	9 <sub>fs</sub>	100	-	-	mmhos	
OYNAMIC CHARACTERISTICS						
Input Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>iss</sub>	-	40	50	pF
Output Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>oss</sub>	-	12	25	
Transfer Capacitance	$(V_{DG} = 25 \text{ Vdc}, V_{GS} = 0, f = 1 \text{ MHz})$	C <sub>rss</sub>	-	3.5	5.0	1
SWITCHING CHARACTERISTIC	S (Note 2)	•	•	•	•	•
Turn-On Delay Time		t <sub>d(on)</sub>	-	-	20	ns
Turn-Off Delay Time	$(V_{DD} = 30 \text{ Vdc}, I_D = 0.2 \text{ Adc},)$	t <sub>d(off)</sub>	_	_	20	

Switching characteristics are independent of operating junction temperature.

# www.BDhtp://chsml.comcom/ON/

### **TYPICAL ELECTRICAL CHARACTERISTICS**



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### **TYPICAL ELECTRICAL CHARACTERISTICS**

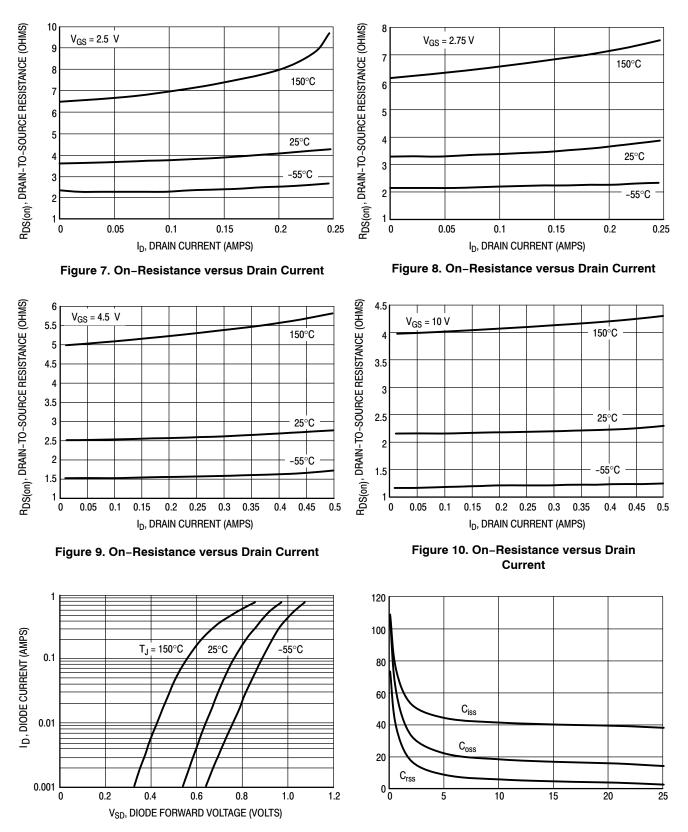


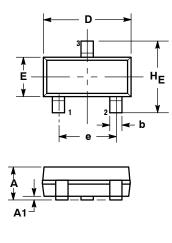
Figure 11. Body Diode Forward Voltage

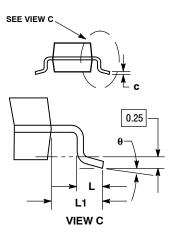
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Figure 12. Capacitance

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

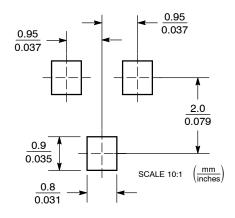
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 21:

PIN 1. GATE 2. SOURCE

3. DRAIN

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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